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Novel 1,8-naphthalimide derivatives for standard-red organic light-emitting device applications[†]

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Three red-emissive $D-\pi$ -A-structured fluorophores with an aromatic amine as the donor, ethene-1,2-divl as the π -bridge, and 1,8-naphthalimide as the acceptor subunit, namely, (E)-6-(4-(dimethylamino)styryl)-2hexyl-1H-benzo[de]isoquinoline-1,3(2H)-dione (Nap1), (E)-2-(2,6-di(isopropyl)phenyl)-6-(4-(dimethylamino)styryl)-1H-benzo[de]isoquinoline-1,3(2H)-dione (Nap2) and (E)-2-(2,6-di(isopropyl)phenyl)-6-(2-(1,1,7,7-tetramethyl-2,3,6,7-tetrahydro-1H,5H-pyrido[3,2,1-ij]quinolin-9-yl)vinyl)-1H-benzo[de]isoquinoline-1,3(2H)-dione (Nap3), were designed and synthesized. In-depth investigations on the correlations between their molecular structures and photophysical characteristics revealed that the presence of an electron-rich 4-dimethylaminophenyl donor moiety in compound Nap1 could endow it with a red emission (e.g., $\lambda_{\text{Pl max}} = 641 \text{ nm}$ in the host-quest blend film with a 14 wt% quest composition); moreover, the replacement of the *n*-hexyl group of Nap1 bonding to the imide nitrogen atom for a more bulky 2,6-di(isopropyl)phenyl one would result in compound Nap2 with more alleviated concentration guenching. Alteration of the 4-(dimethylamino)phenyl donor subunit of Nap2 into a more electron-donating 1,1,7,7-tetramethyljulolidin-9-yl substituent would render compound Nap3 with more improved chromaticity (e.g., λ_{PLmax} = 663 nm in a 14 wt% guest-doped film). Consequently, Nap3 could not only emit standard-red fluorescence with satisfactory chromaticity, but it also showed suppressed intermolecular interactions. Using Nap3 as the dopant, a heavily doped standard-red organic light-emitting diode (OLED) with the device configuration of ITO/MoO3 (1 nm)/TcTa (40 nm)/CzPhONI:Nap3 (14 wt%) (20 nm)/TPBI (45 nm)/LiF (1 nm)/Al (80 nm) was fabricated, and the Commission Internationale de L'Eclairage coordinates, maximum external quantum efficiency and maximum current efficiency of this OLED were (0.67,0.32), 1.8% and 0.7 cd A^{-1} , respectively. All these preliminary results indicated that 1,8-naphthalimide derivatives could act as quite promising standard-red light-emitting materials for OLED applications.

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1. Introduction

Owing to their merits like solid-state self-emission, wide viewing angle, facile color tunability and processability, organic lightemitting devices (OLEDs) have been considered as quite competitive candidates for flat-panel display applications.¹ In comparison

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with phosphorescent OLEDs, fluorescent ones are more suitable with respect to display applications due to their faster response as well as lower efficiency roll-off.² For full-color display applications, it is necessary to develop red, green, and blue fluorescent OLEDs with high efficiency and appropriate chromaticity, yet compared with that of blue^{3a} and green^{3b} devices, the performance of red fluorescent OLEDs with good chromaticity is unsatisfactory. For example, although the current efficiency (CE) of red OLEDs with Commission Internationale de L'Eclairage (CIE) coordinates of (0.63, 0.37) could reach 11.5 cd A⁻¹,⁴ their chromaticity is far from standard-red whose CIE coordinates should be close to (0.67,0.33) according to the stipulation from the National Television Standards Committee. As far as standard-red OLEDs are concerned, although according to a technical report from Idemitsu Kosan Co., high performance devices with CE of 11.0 cd A⁻¹ could be achieved,⁵ no detailed information about the molecular structures of the emitting materials and the device structures could be found.



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In scientific literature reports, the performance of standard-red OLEDs is rather poor with the maximum CE values lower than 3.0 cd A^{-1} and external quantum efficiencies (EQEs) less than 4.0%.⁶ In addition, due to the notorious concentration quenching of the guest fluorophores, the best standard-red OLED bearing guest-host doping structure (CE_{max}: 1.6 cd A^{-1}) has just a low doping-level of 2 wt%;^{6d} hence the manufacturing process should be precisely controlled to acquire good device reproducibility.⁷ Consequently, it is highly desired to exploit novel high performance standard-red fluorophores with suppressed concentration quenching,^{6c,8} so that OLEDs with relatively high doping-levels or even self-hosted device structure could be achieved.

In general, red electrofluorescent materials could be classified into two main categories, namely, compounds bearing polycyclic aromatic hydrocarbon (PAHs) structures and compounds showing intramolecular charge-transfer (ICT) characteristic with D- π -A molecular structures (where D denotes electron-donor and A denotes electron-acceptor).⁸⁻¹⁰ To acquire standard-red fluorescence, PAHs compounds should possess relatively large conjugation systems, e.g., polyacenes^{11a} and porphyrins.^{11b,c} However, to prepare these compounds, delicate synthetic and purifying procedures have to be involved.12 In addition, serious concentration quenching is often observed in these PAHs due to their intense intermolecular interactions.¹⁰ By contrast, ICT-featured red fluorophores bearing D- π -A molecular skeletons have attracted much attention due to their more facile molecular tailoring.¹³ Currently, the reported red electrofluorescent ICTcompounds could be assorted, according to their acceptor constructive units, as maleimide derivatives,14 benzothiadiazole derivatives,15 fumaronitrile derivatives,6,16 and 4-dicyanomethylene-4H-pyran derivatives,¹⁷ etc. However, despite the fact that 1,8-naphthalimide is a widely used acceptor subunit for constructing high performance green¹⁸ and yellow¹⁹ ICT-featured electroluminescent (EL) materials, quite limited success has been achieved in terms of high performance orange and red ones. In 2003, using 1,8-naphthalimide and quinoxaline as the acceptor segments, Lee et al.20 reported an naphthalimide luminogen, but the OLED based on it could only emit orange-red EL with $\lambda_{\text{EL}\,\text{max}}$ of 608 nm. Subsequently, Tian *et al.*²¹ reported that D-A fluorophores with 1,8-naphthalimide as the acceptor subunit could act as red EL materials, yet both the chromaticity and the performance of the OLED were unsatisfactory ($\lambda_{EL max} = 620 \text{ nm}$, L_{max} (maximum brightness) is 15 cd m⁻²). Although in 2005, Cheng et al.22 fabricated red OLEDs with CIE coordinates of (0.63,0.36) using 1,8-naphthalic anhydride derivatives as lightemitting materials, the $\ensuremath{\text{CE}_{\text{max}}}$ of these devices was as low as $0.6 \text{ cd } A^{-1}$. Nevertheless, our recent study has revealed that a 1,8-naphthalimide derivative could act as a high performance orange EL guest material, and the corresponding OLED shows a CE_{max} of 7.2 cd A^{-1} , EQE_{max} of 3.6%, and L_{max} of 16 800 cd m^{-2} .²³ Despite the fact that the CIE coordinates of this device was just (0.56,0.44), its high performance has triggered our speculation that through rational molecular design, 1,8-naphthalimide derivatives may also act as quite promising standard-red EL materials.

Recently, it has been reported that the D- π -A-structured 1,8naphthalimide derivative **NIM** (structure shown in Fig. 1) could



emit intense orange fluorescence in the solid state ($\lambda_{PL,max}$ = 597 nm).²⁴ To construct fluorophores with more red-shifted photoluminescence (PL) emission bands than that of NIM, herein, we altered the 4-(diphenylamino)phenyl (DPAP) donor segment of NIM to be a more electron-rich 4-(dimethylamino)phenyl (DMAP) or 1,1,7,7-tetramethyljulolidin-9-yl (TMJ) donor segment, and constructed three objective compounds (Nap1-3, structures shown in Fig. 1). Moreover, to alleviate the intermolecular interactions, a bulky 2,6-di(isopropyl)phenyl substituent was bonded to the imide nitrogen atom of Nap2 and Nap3. As expected, Nap1-3 all could emit standard-red fluorescence in the thin solid film state, and Nap2 and Nap3 showed more suppressed concentration quenching than Nap1. Using Nap3 as the guest dopant, a high performance standard-red OLED with a relatively heavy doping-level of 14 wt% was achieved. The device had CIE coordinates of (0.67,0.32), EQE_{max} of 1.8%, and a CE_{max} of 0.7 cd A^{-1} , indicating that 1,8-naphthalimide derivatives should be promising candidates as high performance standard-red EL materials.

2. Experimental section

2.1 General information

All the reagents involved in the synthetic procedures were commercially available and used without purification unless otherwise stated. Cyclohexane (CHX), tetrachloromethane, toluene (Tol), chloroform, tetrahydrofuran (THF), dichloromethane (DCM), acetone, N,N-dimethyl formamide (DMF) were of analytical grade and were distilled freshly prior to use. ¹H NMR and ¹³C NMR spectra were obtained on a BRUKER AVANCE AV II-400 MHz spectrometer in DMSO-d₆ or CDCl₃ using TMS as the internal standard. High resolution MS spectra were obtained on a Shimadzu LCMS-IT-TOF spectrometer. FT-IR spectra were obtained on a Perkin-Elmer 2000 infrared spectrometer with KBr pellets under an ambient atmosphere. UV-Vis absorption spectra were obtained on a Perkin-Elmer Lambda 950 scanning spectrophotometer. PL spectra were obtained on a Perkin-Elmer LS55 fluorescence spectrophotometer at 298 K. The absolute PL quantum yields (QYs) of both solution and film samples were determined on a FluoroMax-4 spectrofluorometer (Horiba Jobin Yvon) equipped with an integrating sphere and a digital photometer. Both the fluorimeters have been corrected for the wavelength

dependence of the sensitivity of the detectors and throughput of the monochromators. The **Nap-CzPhONI** composite as well as the **Nap** neat thin film samples were spin-coated from their corresponding chloroform solutions with a concentration of 10 mg mL⁻¹ at a speed of 1500 rpm on quartz substrates for 40 s. Cyclic voltammetry measurements were performed in anhydrous acetonitrile ($5 \times 10^{-4} \text{ mol L}^{-1}$) solutions of **Nap1-3** using 0.10 mol L⁻¹ Bu₄NClO₄ as the supporting electrolyte under a N₂ atmosphere on a LK 2010A electrochemical work station at room temperature, and the three-electrode cell comprised a Pt working electrode, a Pt wire counter electrode, and a Ag/AgNO₃ (0.1 M in acetonitrile) reference electrode. A ferrocene/ferrocenium redox couple was employed as the external standard.

2.2 OLED fabrication and measurements

Indium-tin oxide (ITO) coated glass substrates were cleaned by ultrasonic mixing successively in alcohol, acetone, methanol, and deionized water, followed by UV-ozone oxygen plasma treatment for 2 min before use. Organic functional layers were thermo-evaporated in vacuum (3 \times 10⁻⁴ Pa) with a deposition rate of 0.1 nm s^{-1} . After deposition of the organic layers, the LiF-Al cathode was prepared first by thermal deposition of a LiF thin film (1 nm) followed by the deposition of an Al layer (80 nm). The active area of the OLEDs was $1 \times 1 \text{ mm}^2$. The thicknesses of the organic layers and the cathode were controlled using a quartz crystal thickness monitor. The luminance-voltagecurrent density (L-V-J) characteristics of the OLEDs were measured with a Keithley 2611 Source Meter and a PR705 Spectra Colorimeter, which can also record EL spectra and CIE coordinates accurately. All the measurements on the devices were carried out in an ambient atmosphere without further encapsulation.

2.3 Synthesis

The synthetic routes to **Nap1–3** are outlined in Scheme 1. Intermediates 2, 25 3, 26 5, 27 6^{28} were synthesised according to literature reports.

1,1,7,7-Tetramethyl-9-vinyl-2,3,6,7-tetrahydro-1H,5H-pyrido-[**3,2,1-ij**]**quinolone (4).** *n*-Butyl lithium (1.0 mL of 2.5 mol L⁻¹ in *n*-hexane solution) was added dropwise to a suspension of PPh₃CH₃Br (0.90 g, 2.3 mmol) in anhydrous degassed THF (10.0 mL). The yellow solution was allowed to stir for 30 min,



then a solution of 3 (0.4 g, 1.6 mmol) in 5.0 mL anhydrous degassed THF was added. After being stirred for 20 min, the yellow suspension was poured into saturated aqueous ammonium chloride, and then extracted by petroleum ether (4 × 15 mL). The organic layer was dried over anhydrous Na₂SO₄, and concentrated in vacuum. The resulting crude product was purified by silica gel column chromatography (eluent: petroleum ether/ethyl acetate = 20/1, v/v) to give 4 as a yellowish liquid (0.3 g, 50%). $\delta_{\rm H}$ (400 MHz; CDCl₃; Me₄Si) 7.07 (2H, s, ArH), 6.62 (1H, dd, J_1 = 17.2 Hz, J_2 = 10.8 Hz, =CH), 5.51 (1H, dd, J_1 = 17.6 Hz, J_2 = 1.6 Hz, =CH), 4.99 (d, J_1 = 10.0 Hz, J_2 = 1.6 Hz, 1H, =CH), 3.18 (t, J = 6.0 Hz, 6H, -NCH₂), 1.45 (t, J = 6.0 Hz, 1H, Ar-CH₂), 1.30 (s, 12H, -CH₃).

(E)-6-(4-(Dimethylamino)styryl)-2-hexyl-1H-benzo[de] isoquinoline-1,3(2H)-dione (Nap1). A Schlenk flask was charged with a mixture of 2 (0.13 g, 0.9 mmol), 5 (0.30 g, 0.9 mmol), Pd(OAc)₂ (3.5 mg, 0.02 mmol), P(o-tolyl)₃ (8.3 mg, 0.03 mmol), triethylamine (6.0 mL) and N,N-dimethylformamide (DMF) (7.0 mL). The reaction mixture was heated at 90 °C for 24 h under argon. After being cooled to room temperature, the mixture was poured into water (100 mL), extracted by dichloromethane $(4 \times 20 \text{ mL})$ and then organic phase was combined and washed with brine and then dried over anhydrous Na₂SO₄. After the solvent was removed under vacuum, the crude product was purified by column chromatography over a silica gel (eluent: petroleum ether/dichloromethane = 15/1, v/v), followed by recrystallization from a mixture of cyclohexane and dichloromethane to afford pure Nap1 as a red solid (0.1 g, 30%). $\delta_{\rm H}$ (400 MHz; DMSO-*d*₆; Me₄Si) 9.00 (1H, d, *J* = 9.2 Hz, ArH), 8.53 (1H, d, J = 7.2 Hz, ArH), 8.45 (1H, d, J = 8.0 Hz, ArH), 8.21 (1H, d, *J* = 8.4 Hz, ArH), 7.96 (1H, d, *J* = 16.0 Hz, ==CH), 7.89 (1H, t, *J*₁ = 7.6 Hz, *J*₂ = 8.0 Hz, ArH), 7.71 (2H, d, *J* = 8.4 Hz, ArH), 7.55 (1H, d, J = 16.0 Hz, ==CH), 6.89 (2H, d, J = 8.4 Hz, ArH), 4.05 (2H, t, J = 7.2 Hz, -NCH₂), 3.00 (6H, s, -NMe₂), 1.64 (m, 2H, -CH₂, -CH₃), 1.31 (m, 6H, $-CH_2$), 0.87 (m, 3H, $-CH_3$). δ_C (100 MHz; CDCl₃; Me₄Si) 164.4, 164.2, 150.9, 142.4, 135.6, 131.2, 131.0, 130.1, 129.4, 128.9, 128.5, 126.3, 124.8, 123.1, 122.9, 118.4, 112.2, 40.5, 40.3, 31.6, 28.1, 26.8, 22.6, 14.1. FT-IR $\nu_{\text{max}}/\text{cm}^{-1}$ 1655 (C=O), 1358 (C-N). HRMS (ESI)⁺ m/z: calcd for $[M + H]^+$: $C_{28}H_{31}N_2O_2^+$, 427.2380; found, 427.2365.

(E)-2-(2,6-Di(isopropyl)phenyl)-6-(4-(dimethylamino)styryl)-1H-benzo[de]isoquinoline-1,3(2H)-dione (Nap2). Compound Nap2 was prepared as a red solid with a yield of 50% using a similar procedure for the synthesis of Nap1, but with 5 rather than 6 as the reactant. $\delta_{\rm H}$ (400 MHz; DMSO- d_6 ; Me₄Si) 9.11 (1H, d, J = 8.8 Hz, ArH), 8.59 (1H, d, J = 6.8 Hz, ArH), 8.50 (1H, d, *J* = 8.0 Hz, ArH), 8.25 (1H, d, *J* = 8.0 Hz, ArH), 8.01 (1H, d, *J* = 16.0 Hz, ==CH), 7.93 (1H, t, *J*₁ = 6.4 Hz, *J*₂ = 8.0 Hz, ArH), 7.73 (2H, d, J = 8.8 Hz, ArH), 7.60 (1H, d, J = 15.6 Hz, ==CH), 7.45 (1H, t, J = 7.6 Hz, ArH), 7.33 (2H, d, J = 7.6 Hz, ArH), 6.78 (2H, d, J = 8.8 Hz, ArH), 3.00 (6H, s, -NMe₂), 2.66 (2H, m, Ar-CH) 1.05 (12H, d, J = 6.8 Hz, $-CH_3$). δ_C (100 MHz; $CDCl_3$; Me₄Si) 164.4, 164.2, 145.7, 142.8, 135.9, 131.7, 131.6, 131.1, 130.4, 129.6, 129.6, 129.4, 128.6, 126.4, 124.0, 123.1, 123.0, 120.4, 118.4, 112.4, 40.4, 29.1, 24.0, 8.1. FT-IR $\nu_{\text{max}}/\text{cm}^{-1}$ 1661 (C=O), 1352 (C-N). HRMS (ESI)⁺ m/z: calcd for $[M + H]^+$: C₃₄H₃₅N₂O₂⁺, 503.2693; found, 503.2676.

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(E)-2-(2,6-Di(isopropyl)phenyl)-6-(2-(1,1,7,7-tetramethyl-2,3,6,7tetrahydro-1H,5H-pyrido[3,2,1-ij]quinolin-9-yl)vinyl)-1H-benzo[de]isoquinoline-1,3(2H)-dione (Nap3). Compound Nap3 was prepared as a dark red solid with a yield of 24% using a similar procedure as the synthesis of Nap1, but with 4 and 6 rather than 2 and 5 as the reactants. The crude product was purified by column chromatography over a silica gel (eluent: petroleum ether/dichloromethane = 15/1, v/v), followed by recrystallization from a mixture of *n*-hexane and dichloromethane three times. $\delta_{\rm H}$ (400 MHz; DMSO- d_6 ; Me₄Si) 9.16 (1H, d, J = 8.4 Hz, ArH), 8.60 (1H, d, J = 7.2 Hz, ArH), 8.49 (1H, d, J = 8.0 Hz, ArH), 8.25 (1H, d, J = 8.0 Hz, ArH), 7.95 (2H, m, ArH, ==CH), 7.57 (1H, d, J = 16.0 Hz, ==CH), 7.52 (2H, s, ArH), 7.45 (1H, t, J₁ = 7.6 Hz, ArH), 7.34 (2H, d, *J* = 7.6 Hz, ArH), 3.23 (4H, t, *J*₁ = 6.4 Hz, *J*₂ = 6.0 Hz, -NCH₂), 2.67 (2H, m, Ar-CH), 1.73 (4H, t, J₁ = 5.6 Hz, J₂ = 6.0 Hz, Ar-CH₂), 1.32 (12H, s, -CH₃), 1.06 (12H, d, J = 4.0 Hz, -CH₃). $\delta_{\rm C}$ (100 MHz; CDCl₃; Me₄Si) 164.5, 164.2, 145.7, 143.2, 137.0, 131.8, 131.6, 131.1, 130.5, 129.6, 129.4, 126.3, 123.9, 123.3, 123.1, 122.8, 119.9, 117.0, 46.8, 36.4, 32.3, 30.8, 29.1, 24.0. FT-IR $\nu_{\text{max}}/\text{cm}^{-1}$ 1661 (C=O), 1576 (C-N). HRMS (ESI)⁺ m/z: calcd for $[M + H]^+$: $C_{42}H_{47}N_2O_2^+$, 611.3632; found, 611.3618.

Results and discussion

3.1 Photophysical properties in dilute solutions

The UV-Vis absorption spectra of Nap1-3 in dilute solutions of different polarities are illustrated in Fig. 2, and the corresponding data are summarized in Table 1. In a similar solvent, the absorption maximum ($\lambda_{abs max}$) of Nap2 is slightly redshifted (~7 nm) compared with that of **Nap1**, but the $\lambda_{abs max}$ of Nap3 was considerably red-shifted (>30 nm) compared to those of Nap1 and Nap2. Therefore, the replacement of the *n*-hexyl bonding to the imide nitrogen atom into a 2,6-di(isopropyl) phenyl group would just bring a little effect on the conjugation length of these compounds, but the presence of a TMJ rather than a DMAP donor subunit in Nap3 would endow it with a much extended π -conjugation system. As expected, in every solvent, the absorption bands of all the three objective compounds were redshifted compared to that of NIM,²⁴ confirming that the bandgaps of Nap1-3 are narrower than that of NIM, which should be chiefly attributed to the more electron-donating capability of DMAP and TMJ groups than that of DPAP. With an increase in solvent polarity from cyclohexane (CHX) to dichloromethane (DCM), the absorption bands of Nap1-3 showed 20-30 nm red-shifts, indicative of the ICT character of the three compounds in their ground states.20,29

Consistent with the absorption characteristics of **NIM** and **Nap1–3**, the PL emission maximum ($\lambda_{PL max}$) of **Nap3** was more bathochromically-shifted (~30 nm) that hat of **Nap2** or **Nap1** in every solvent, the $\lambda_{PL max}$ of **Nap2** was just slightly (3–5 nm) red-shifted compared to **Nap1**, and the $\lambda_{PL max}$ s of **Nap1–3** are significantly red-shifted compared to **NIM** (Fig. 3 and Table 1). In comparison with their absorption spectra, the fluorescent spectra of **Nap1–3** show more significant positive solvatochromism (*e.g.*, for **Nap3**: $\lambda_{PL max} = 553$ nm in CHX; $\lambda_{PL max} = 622$ nm



Fig. 2 Normalized absorption spectra of the three objective compounds in solvents with different polarities. (a) Nap1; (b) Nap2; and (c) Nap3.

in toluene; $\lambda_{PL max} = 680$ nm in chloroform; $\lambda_{PL max} = 722$ nm in DCM; and $\lambda_{PL max} = 750$ nm in acetone), indicating a strong ICT character of the lowest singlet excited states of Nap1-3. This deduction was further confirmed by the Lippert-Mataga plots of Nap1-3 (see Fig. S1, ESI[†]), since good linear correlations between the solvent polarity parameter and Stokes shifts could be achieved in all these Nap systems. It should be pointed out that in solvents with moderate polarity like chloroform and tetrahydrofuran (THF), Nap1-3 could emit red fluorescence with high PL quantum yields (PLQY, Φ_{PL}). For example, in THF solution, both Nap1 and Nap2 showed $\lambda_{PL max}$ values >650 nm and $\Phi_{\rm PL}$ values >0.5, and the chloroform solution of **Nap3** displayed a $\lambda_{PL max}$ of 680 nm and a Φ_{PL} of 0.45. With further increased solvent polarity to acetone, the PL emission spectra of Nap1-3 were all observed to shift towards the near infrared region approaching \sim 750 nm, but their $\Phi_{\rm PL}$ s were found to decrease drastically, which might arise from the much intensified non-radiative internal conversion processes in these compounds due to their much lowered energy gaps.9 Nevertheless, taking into consideration that Nap1-3 could emit highly efficient red fluorescence in solvents with medium polarity, they might act as promising red EL materials.

Table 1 Photophysical data of the three objective molecules in solvents with different polarities (1.0×10^{-5} mol L⁻¹)

	NIM ^a			Nap1			Nap2			Nap3		
Solvent	$\overline{\lambda_{absmax}}$ (nm)	$\lambda_{PL \max} (nm)$	$\Phi_{ m PL}$	$\lambda_{absmax}(nm)$	$\lambda_{PL \max} (nm)$	$\Phi_{ m PL}$	$\lambda_{absmax}(nm)$	$\lambda_{PL \max} (nm)$	$\Phi_{ m PL}$	$\overline{\lambda_{absmax}}$ (nm)	$\lambda_{PL \max} (nm)$	$\Phi_{ m PL}$
CHX	_	_	_	440	514	0.22	447	517	0.16	479	553	0.24
CCl_4	_	_	_	450	543	0.29	457	546	0.28	488	567	0.42
Tol	448	552	0.81	461	580	0.42	468	585	0.42	505	622	0.24
$CHCl_3$	461	624	0.36	471	634	0.62	479	637	0.64	511	680	0.45
THF	450	607	0.54	466	655	0.59	473	658	0.54	510	696	0.29
CH_2Cl_2	_	_		470	669	0.51	477	672	0.50	519	722	0.09
Acetone	448	658	0.06	464	698	0.08	471	702	0.08	510	750	0.00

^{*a*} Photophysical data derived from ref. 24; $\lambda_{abs max}$: absorption maximum; $\lambda_{PL max}$: PL emission maximum; Φ_{PL} : absolute PL quantum yield.





Fig. 3 Normalized PL emission spectra of the three objective compounds in solvents with different polarities. (a) Nap1; (b) Nap2; and (c) Nap3.

3.2 PL emission properties in crystalline powder and thin film states

To investigate their potential as red light-emitting materials in OLEDs, PL emission spectra of **Nap1-3** in crystalline powder and thin film states were obtained. As shown in Fig. 4 and Table 2, in both powder and film states, all the three compounds could emit standard-red fluorescence with $\lambda_{PL max}$ of 660–700 nm, and **Nap3** shows the most red-shifted emission band. In each case, the PL spectrum of the film sample of **Nap**

was slightly broader and red-shifted than that of the crystalline powder sample, which should be attributed to the different

molecular conformations in the crystalline and amorphous

samples of Nap1–3 (λ_{ex} = 490 nm). (a) Nap1; (b) Nap2; and (c) Nap3.

states.³⁰ Despite the fact that in dilute solutions, the fluorescence band of **Nap2** was slightly red-shifted compared to **Nap1**, its $\lambda_{PL \max}$ was observed to be 6 nm blue-shifted compared to **Nap1** in the neat film state (669 nm *vs.* 675 nm), and its Φ_{PL} was also higher than that of **Nap1** (0.02 *vs.* 0.01). Hence, we could infer

 Table 2
 Fluorescence data and PLQYs of Nap-CzPhONI blend films, neat films and crystalline powders of the three objective molecules

	Nap1		Nap2		Nap3		
Doping ratio (wt%)	$\lambda_{\rm PL max}^{a}$ (nm)	${\Phi_{ m PL}}^a$	$\lambda_{\rm PL max}^{a}$ (nm)	${\Phi_{ m PL}}^a$	$\lambda_{\rm PL max}^{a}$ (nm)	${\Phi_{ m PL}}^a$	
2	613	0.37	608	0.46	646	0.23	
4	622	0.29	612	0.38	655	0.21	
14	641	0.16	632	0.27	663	0.15	
Neat film	678	0.01	673	0.02	703	0.01	
Powder	659	0.01	659	0.04	680	0.02	

 a $\lambda_{\rm ex}$ = 390 nm for the blend films; $\lambda_{\rm ex}$ = 490 nm for the neat films and crystalline powders.



Fig. 5 Device configuration and energy band diagram of devices I, II, and III (left); and molecular structure of the host compound **CzPhONI** (right).

that the presence of the more bulky 2,6-di(isopropyl)phenyl rather than a *n*-hexyl group in **Nap2** should be propitious to the suppression of intermolecular interactions of these fluorophores, and hence could promote less concentration quenching. Although the $\Phi_{PL}s$ of these neat film samples were rather low (≤ 0.02), which would limit their potential as high-performance non-doped red EL luminogens, the relatively high $\Phi_{PL}s$ of **Nap1-3** in medium-polarity solvents spurred us to prepare guest–host composite films using **Nap1-3** as dopants. As the compound **CzPhONI** (structure shown in Fig. 5) we have developed recently is a high performance host material for an orange naphthalimide guest compound;²³ herein, we chose it as the host material to fabricate **Nap-CzPhONI** guest–host composite films with different doping-levels.

As shown in Fig. 4 and Table 2, for all the three compounds, with increasing concentration of Nap from 2 wt% to 14 wt%, the $\lambda_{PL max}$ of the corresponding Nap–CzPhONI composite film red-shifted gradually. Excitingly, at a relatively high dopinglevel of 14 wt%, the film samples with Nap1 and Nap2 as guests could emit red fluorescence with $\lambda_{PL max}$ of 630–640 nm and the 14 wt% Nap3 composite film could emit standard-red fluorescence with satisfactory chromaticity ($\lambda_{PL max} = 663$ nm). Analogous to the PL emission property of their neat films, in every doping-level, the $\lambda_{PL max}$ of Nap2 was observed to be blue-shifted for 5-10 nm than that of Nap1, validating the more suppressed intermolecular interactions in Nap2 than Nap1. In composite films with Nap1 and Nap2 as guests, no emission from the CzPhONI host $(\lambda_{PLmax} \sim 500 \text{ nm})^{23}$ could be discerned at each doping-level, indicative of the efficient energy transfer between the host and guest compounds. While for CzPhONI/Nap3 composite films, the emission band from CzPhONI was discernible at a relatively low doping-level of 2 wt%; hence, the energy transfer

efficiency between CzPhONI and Nap3 should not have been as high as that between CzPhONI and Nap1/Nap2.

In comparison with those of the neat films, the $\Phi_{PL}s$ of the guest-host blend film samples were much improved (Table 2). For all the three compounds, the highest PLQYs of the blend films were obtained at the lowest doping-level of 2 wt%. With increasing guest doping ratios from 2 wt% to 14 wt%, the Φ_{PL} of **Nap1**-based film dropped considerably from 0.37 to 0.16, while the $\Phi_{PL}s$ of **Nap2**- and **Nap3**-based samples were lowered from 0.46 to 0.27 and from 0.23 to 0.15, respectively, both were less significant than that of the **Nap1**-based one, indicating that **Nap2** and **Nap3** showed more alleviated self-quenching relative to **Nap1**. Consequently, owing to the concurrent presence of a strong electron-donating TMJ group and a bulky 2,6-di(isopropyl)-phenyl substituent, **Nap3** possesses not only an extended π -conjugation system, but also alleviated concentration quenching; hence, it is a perspective candidate as a standard-red EL material.

3.3 Electrochemical properties

To estimate the energy levels of the frontier orbitals of Nap1-3, their electrochemical properties were investigated by cyclic voltammetry (CV) in degassed 5×10^{-4} mol L⁻¹ anhydrous acetonitrile solutions with the Fc/Fc⁺ redox couple as the external standard, and the cyclic voltammograms are shown in Fig. S2 (in ESI[†]). During the anodic scan from 0 V to 0.50 V, both Nap1 and Nap2 showed reversible oxidation waves with half wave potentials $(E_{1/2})$ of 0.24 V vs. Fc/Fc⁺, but Nap3 showed a reversible oxidation wave with $E_{1/2}$ of 0.05 V vs. Fc/Fc⁺. Upon cathodic scanning from 0 V to -1.95 V, Nap1 showed a reversible reduction wave with $E_{1/2}$ of -1.70 V vs. Fc/Fc⁺, while both Nap2 and Nap3 showed reversible reduction waves with $E_{1/2}$ of -1.66 V vs. Fc/Fc⁺. Hence, the calculated electrochemical band-gaps of Nap1-3 were 1.94 eV, 1.90 eV and 1.71 eV in sequence, which were consistent with their optical bandgaps (2.19 eV, 2.17 eV and 1.85 eV for Nap1-3 in sequence) deduced from the onset of their UV-Vis absorption spectra in dilute acetonitrile solutions (Fig. S3 in ESI[†]).

In comparison with the Fc/Fc⁺ redox couple whose energy level is -4.88 eV in vacuum,³¹ the HOMO energy levels of **Nap1-3** were calculated to be -5.12 eV, -5.12 eV and -4.93 eV, and their LUMO energy levels are calculated to be -3.18 eV, -3.22 eV and -3.22 eV, respectively. As the HOMO and LUMO energy levels of **CzPhONI** are -5.60 eV and -3.10 eV, respectively,²³ the HOMO energy difference between **CzPhONI** and **Nap1-3** was 0.48 eV, but that between the HOMOs of **CzPhONI** and **Nap3** was as large as 0.67 eV. Hence, **CzPhONI** should be a more ideal host material for **Nap1-2** than **Nap3**, which may account for the more efficient energy transfer process between **CzPhONI** and **Nap1-2** than **Nap3**.

3.4 Electroluminescent properties

Based on these photophysical and electrochemical experimental results, thermo-evaporated OLEDs with a **Nap3–CzPhONI** composite film as light-emitting layer (EML) were fabricated. The device structure was ITO/MoO₃ (1 nm)/TcTa (40 nm)/C**zPhONI**: **Nap3** (x wt%) (20 nm)/TPBI (45 nm)/LiF (1 nm)/Al (80 nm), wherein TcTa (4,4',4"-tri(*N*-carbazolyl)triphenylamine) served as

the hole-transporting material (HTM) and TPBI (1,3,5-tris(1phenyl-1*H*-benzo[*d*]imidazol-2-yl)benzene) served as the electrontransporting material (ETM). The energy level diagram of the devices is shown in Fig. 5. According to the PL characterization results, device **I**, **II** and **III** with **Nap3** concentrations of 2 wt%, 4 wt% and 14 wt%, respectively, were prepared. The EL spectra and the luminance–voltage–current density (L–V–J) characteristics of devices **I–III** are shown in Fig. 6, and some representative EL performance data are summarized in Table 3.

Devices I-III all displayed bias-independent EL spectra with $\lambda_{\rm EL\,max}$ of 636 nm, 644 nm and 657 nm (vide Fig. 6a and Fig. S4 in ESI†), and CIE coordinates of (0.62,0.37), (0.65,0.34) and (0.67,0.32), respectively. Hence, devices I and II can emit red EL, but device III shows standard-red EL with satisfactory chromaticity. Compared with the corresponding PL spectra of their EML, the EL spectra of all the devices are much broadened and slightly blue-shifted. Because the emission band of Nap3 correlated highly with the environmental polarity and the EML of the OLEDs was as thin as 20 nm, carrier recombination may have occurred not only within the EML, but also at the TcTa/EML or EML/TPBI interfaces; this may account for the



Fig. 6 (a) EL spectra of the three devices (under driving current density of 0.5 mA cm^{-1}); (b) luminance–voltage–current density characteristics of the devices.

Table 3	EL characteristics	of the d	devices	using N	lap3 a	as the g	juest dopar	۱t
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Device	$V_{\mathrm{on}}\left(\mathbf{V}\right)$	$L_{\rm max}$ (cd m ⁻²)	EQE _{max} (%)	$\begin{array}{c} {\rm CE}_{\max} \\ ({\rm cd} \ {\rm A}^{-1}) \end{array}$	$\lambda_{\rm ELmax}$ (nm)	CIE (x,y)
I	3.1	10 900	2.1	1.9	636	(0.62,0.37)
II	3.1	6600	1.8	1.1	644	(0.65, 0.34)
III	3.1	2660	1.8	0.7	657	(0.67,0.32)

broadened and blue-shifted EL spectra of these devices. In addition, although the emission from CzPhONI is discernible in the PL spectrum of the 2 wt% Nap3-CzPhONI composite film, it could not be observed in the EL spectrum of device I, indicative of the more efficient energy transfer and/or charge carrier trapping on Nap3 in the EL process. As shown in Fig. 6b, under similar driving voltages, the current density of device II was lower than that of device I. but that of the more heavily doped device III is comparable with that of device I. Consequently, it should be the energy transfer mechanism that dominates the EL emission process in device I and II whose guest doping-levels are relatively low, but it should be the direct charge carrier trapping mechanism that governs the EL process in device III.³² In fact, according to the energy level diagram of the devices (Fig. 5), Nap3 should act as efficient hole-carrier traps due to its much higher HOMO energy level than that of the host and HTM.

All the three devices display comparable turn-on voltages of 3.1 V. Device I exhibits relatively high EL performance with L_{max} , CE_{max} and EQE_{max} of 10 900 cd m⁻², 1.9 cd A⁻¹ and 2.1%, respectively, indicating that Nap3 is a quite promising guest compound for OLED applications. However, the chromaticity of this device was still unsatisfactory. With increasing dopinglevel to 4 wt%, the resulting device II showed EL that approaches a standard-red emission with Lmax, CEmax and EQEmax values of 6600 cd m⁻², 1.1 cd A⁻¹ and 1.8%, respectively. For device III with a further increased doping-level, it could emit standard-red EL with a L_{max} of 2660 cd m⁻², CE_{max} of 0.7 cd A⁻¹, and EQE_{max} of 1.8%. It should be pointed out that compared with the state-of-art standard-red electrofluorescent OLEDs, the PLOYs of the active layers using Nap3 as a guest dopant were unsatisfactory, which may eventually limit the efficiency of the devices. Nevertheless, as the dilute chloroform solution of Nap3 could emit standard-red fluorescence with a $\varPhi_{\rm PL}$ value of $\,\sim$ 0.45, the PLQY of the EML with Nap3 as the guest compound might be enhanced drastically if more appreciate host material were used. Moreover, the device structure, doping level and layer thickness used here have not been optimized for either low driving voltage or high efficiency, thus much improved EL performance should be expected after further optimization has been carried out to resolve these issues.

4. Conclusions

Using electron-rich arylamino groups as the donor constructive units, three red-emissive naphthalimide derivatives were designed and synthesized, and correlations between the molecular structures and photophysical properties of these compounds have been investigated. The results indicated that the presence of a more electron-donating 1,1,7,7-tetramethyljulolidin-9-yl in these fluorophores would endow them with more red-shifted emission bands, while the presence of a bulky 2,6-di(isopropyl)phenyl group on the imide nitrogen atom of these luminogens would reduce their intermolecular interactions. Consequently, the objective compound **Nap3** bearing both 1,1,7,7-tetramethyljulolidin-9-yl and 2,6-di(isopropyl)phenyl groups not only showed standard-red fluorescence with satisfactory chromaticity, but it also showed suppressed concentration quenching behaviour. Using **Nap3** as the guest dopant, a heavily doped standard-red OLED was achieved with CIE coordinates, EQE_{max} and CE_{max} values of (0.67,0.32), 1.8% and 0.7 cd A^{-1} , respectively. To the best of our knowledge, this is the first example of a standard-red-emissive 1,8-naphthalimide derivative for OLED applications. All these preliminary results indicated that through rational molecular design, 1,8-naphthalimide derivatives could act as quite promising standard-red light-emitting materials for OLED applications.

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